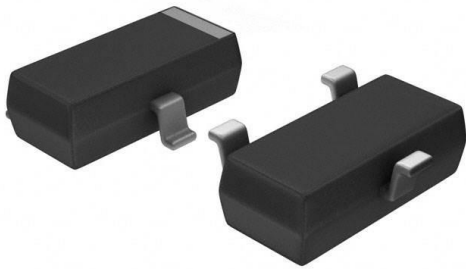


# MMBT5401-HF Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	MMBT5401-HF-DG
Manufacturer	<a href="#">Comchip Technology</a>
Manufacturer Product Number	MMBT5401-HF
Description	TRANS PNP 160V 0.6A SOT23-3
Detailed Description	Bipolar (BJT) Transistor PNP 160 V 600 mA 300MHz 300 mW Surface Mount SOT-23-3



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

DiGi is a global authorized distributor of electronic components.



## Purchase and inquiry

Manufacturer Product Number:

MMBT5401-HF

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

160 V

Current - Collector Cutoff (Max):

50nA (ICBO)

Power - Max:

300 mW

Operating Temperature:

150°C (TJ)

Package / Case:

TO-236-3, SC-59, SOT-23-3

Base Product Number:

MMBT5401

Manufacturer:

Comchip Technology

Product Status:

Active

Current - Collector (Ic) (Max):

600 mA

Vce Saturation (Max) @ Ib, Ic:

500mV @ 5mA, 50mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

100 @ 10mA, 5V

Frequency - Transition:

300MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-23-3

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

ECCN:

EAR99

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0075

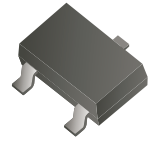
# General Purpose Transistors



## MMBT5401-HF (PNP)

RoHS Device

Halogen Free



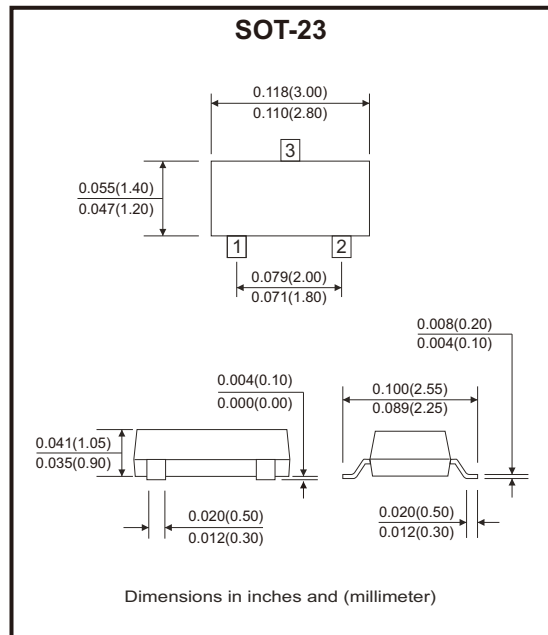
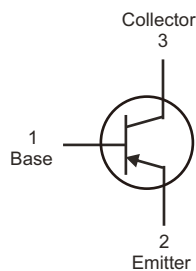
### Features

- Epoxy meets UL-94 V-0 flammability rating.
- Moisture sensitivity Level 1.

### Mechanical data

- Case: SOT-23, molded plastic.
- Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102.

### Circuit Diagram



### Maximum Ratings (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Value	Unit
Collector-base voltage	$I_C = -100\mu\text{A}$ , $I_E = 0$	$V_{CB0}$	-180	V
Collector-emitter voltage	$I_C = -1\text{mA}$ , $I_B = 0$	$V_{CE0}$	-160	V
Emitter-base voltage	$I_E = -10\mu\text{A}$ , $I_C = 0$	$V_{EB0}$	-6	V
Collector current		$I_C$	-600	mA
Collector power dissipation		$P_C$	300	mW
Operation junction temperature		$T_J$	150	$^\circ\text{C}$
Storage temperature range		$T_{STG}$	-55 to +150	$^\circ\text{C}$
Thermal resistance from junction to ambient		$R_{\theta JA}$	417	$^\circ\text{C/W}$

# General Purpose Transistors

## Electrical Characteristics (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-base voltage	$V_{CBO}$	$I_C = -100\mu\text{A}$ , $I_E = 0$	-180			V
Collector-emitter voltage	$V_{CEO}$	$I_C = -1\text{mA}$ , $I_B = 0$	-160			V
Emitter-base voltage	$V_{EBO}$	$I_E = -10\mu\text{A}$ , $I_C = 0$	-6			V
Collector-base cut-off current	$I_{CBO}$	$V_{CB} = -120\text{Vdc}$			-50	nA
Emitter-emitter cut-off current	$I_{EBO}$	$V_{EB} = -4\text{Vdc}$			-50	nA
DC current gain	$h_{FE(1)}$	$V_{CE} = -5\text{Vdc}$ , $I_C = -1\text{mA}$	80			
	$h_{FE(2)}$	$V_{CE} = -5\text{Vdc}$ , $I_C = -10\text{mA}$	100		300	
	$h_{FE(3)}$	$V_{CE} = -5\text{Vdc}$ , $I_C = -50\text{mA}$	50			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -10\text{mA}$ , $I_B = -1\text{mA}$			-0.2	V
		$I_C = -50\text{mA}$ , $I_B = -5\text{mA}$			-0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = -10\text{mA}$ , $I_B = -1\text{mA}$			-1.0	V
		$I_C = -50\text{mA}$ , $I_B = -5\text{mA}$			-1.0	V
Transition frequency	$f_r$	$V_{CE} = -5\text{Vdc}$ , $I_C = -10\text{mA}$ , $f = 30\text{MHz}$	100		300	MHz

## Rating and Characteristic Curves (MMBT5401-HF)

Fig.1 - Static Characteristic

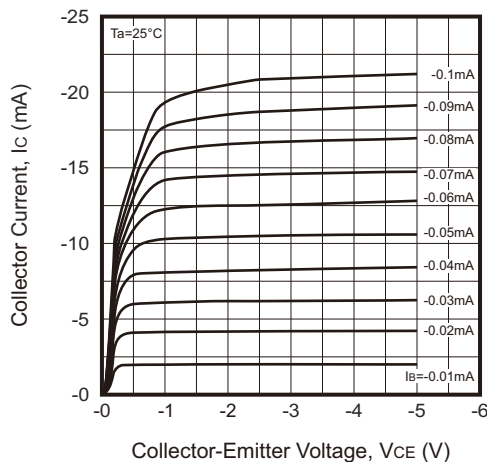
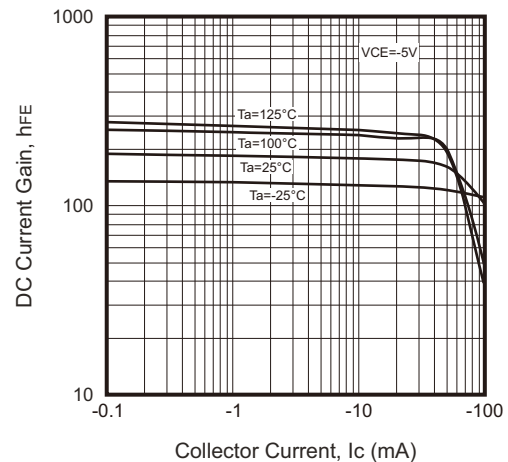


Fig.2 - DC Current Gain



# General Purpose Transistors



## Rating and Characteristic Curves (MMBT5401-HF)

Fig.3 - Collector-Emitter Saturation Voltage

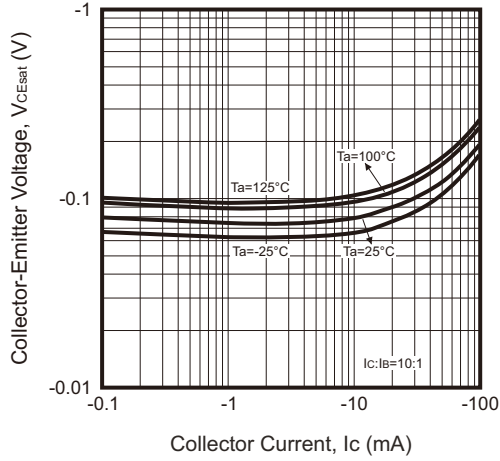


Fig.4 - Base-Emitter Saturation Voltage

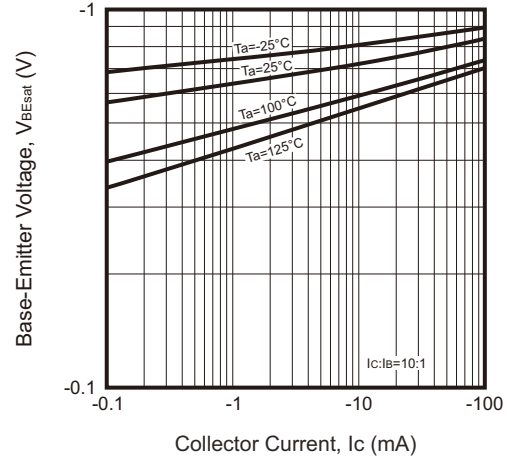


Fig.5 - Base-Emitter on Voltage

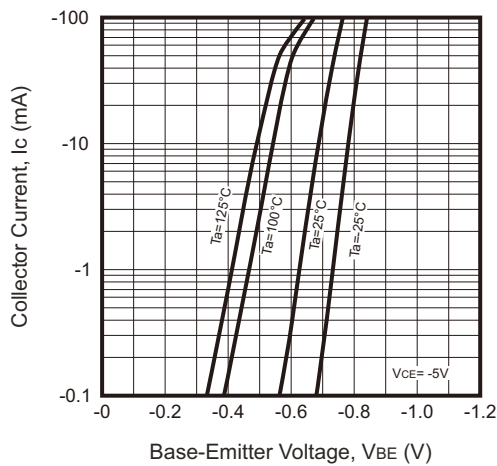


Fig.6 -  $C_{ob}/C_{ib} \text{ --- } V_{CB}/V_{EB}$

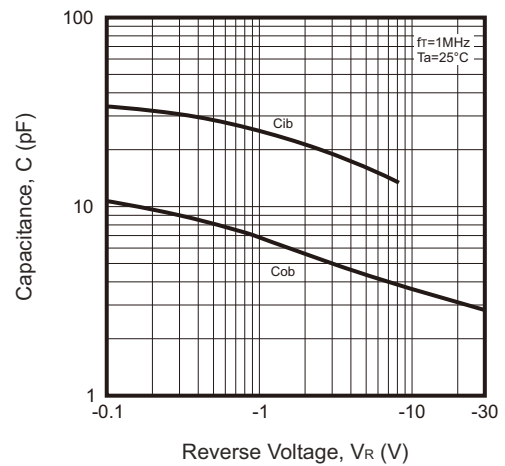
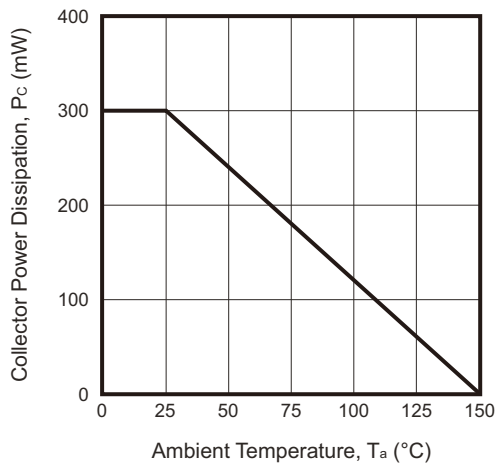


Fig.7 - Collector Power Derating Curve



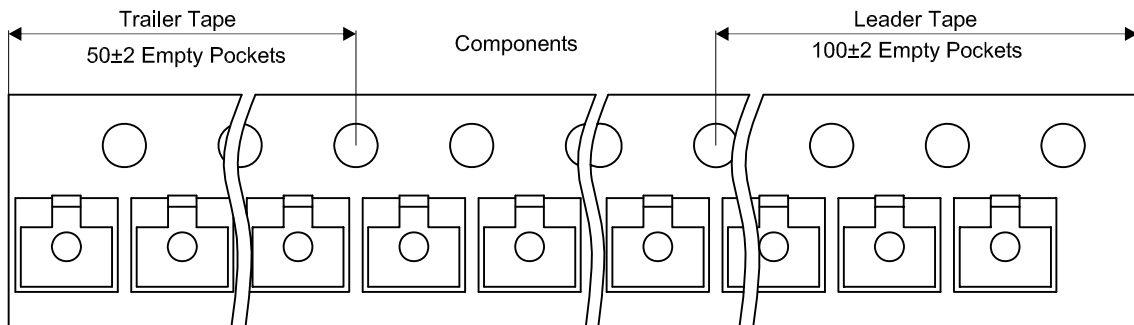
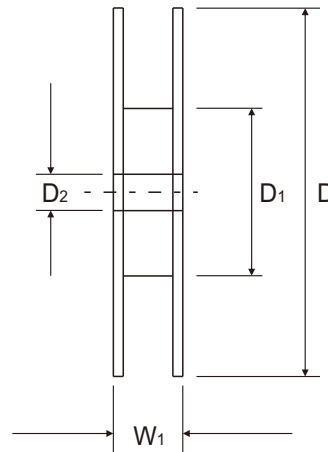
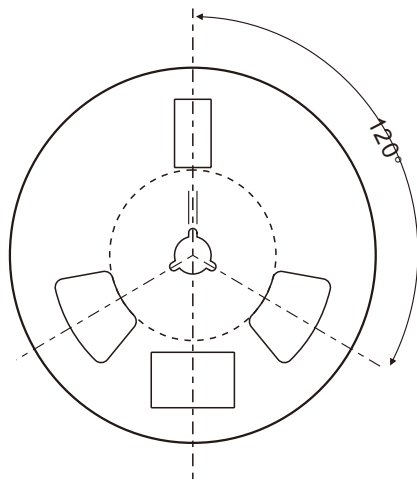
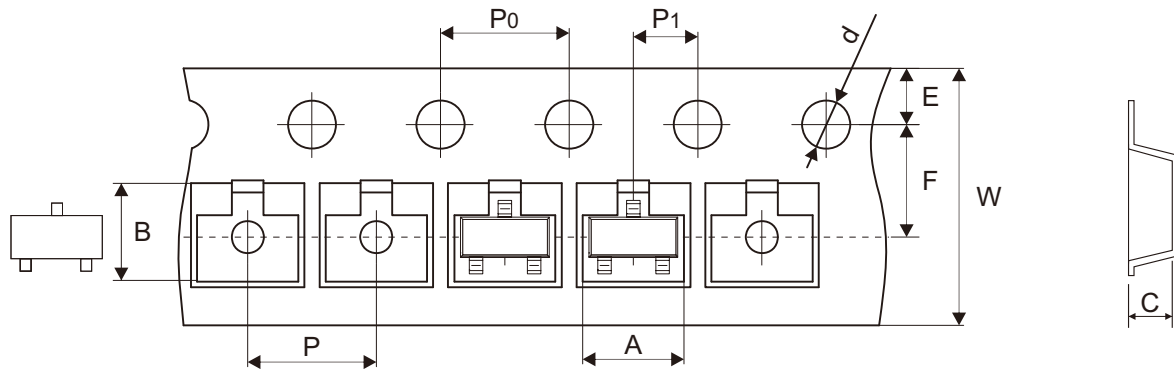
Company reserves the right to improve product design , functions and reliability without notice.

REV:B

# General Purpose Transistors



## Reel Taping Specification



SOT-23	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	$3.15 \pm 0.10$	$2.77 \pm 0.10$	$1.22 \pm 0.10$	$1.50 + 0.10 - 0.00$	$178.00 \pm 1.00$	$54.60 \pm 1.00$	$13.30 \pm 1.00$
	(inch)	$0.124 \pm 0.004$	$0.109 \pm 0.004$	$0.048 \pm 0.004$	$0.059 + 0.004 - 0.000$	$7.008 \pm 0.039$	$2.150 \pm 0.039$	$0.524 \pm 0.039$

SOT-23	SYMBOL	E	F	P	P0	P1	W	W1
	(mm)	$1.75 \pm 0.10$	$3.50 \pm 0.05$	$4.00 \pm 0.10$	$4.00 \pm 0.10$	$2.00 \pm 0.05$	$8.00 + 0.30 - 0.10$	$11.10 \pm 0.20$
	(inch)	$0.069 \pm 0.004$	$0.138 \pm 0.002$	$0.157 \pm 0.004$	$0.157 \pm 0.004$	$0.079 \pm 0.002$	$0.315 + 0.012 - 0.004$	$0.437 \pm 0.008$

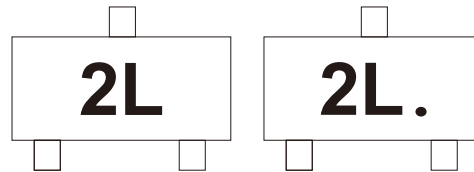
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REV:B

# General Purpose Transistors

## Marking Code

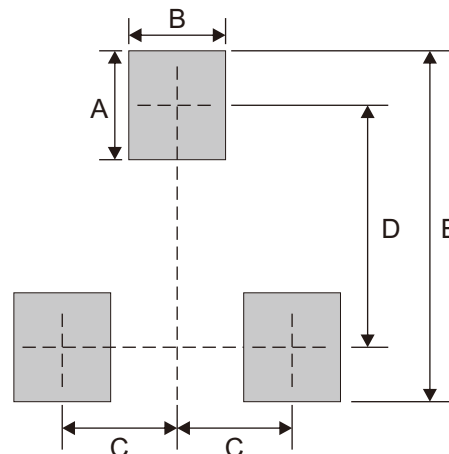
Part Number	Marking Code
MMBT5401-HF	2L



Solid dot = Control code

## Suggested P.C.B. PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.90	0.035
B	0.80	0.031
C	0.95	0.037
D	2.00	0.079
E	2.90	0.114



Note: 1. The pad layout is for reference purposes only.

## Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-23	3,000	7



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